



EVL3435-L-00A

19A, 22V, Fixed-Frequency, High-Efficiency, Fully Integrated, Synchronous Boost Converter Evaluation Board

DESCRIPTION

The EVL3435-L-00A is an evaluation board designed to demonstrate the capabilities of the MP3435, a 600kHz, fixed-frequency, high-efficiency, fully integrated synchronous boost converter with 22V of output voltage across a wide input supply range (3V to 20V). The MP3435 features input disconnect to provide additional protection during an output short or shutdown by isolating the input from the output. For battery-operated applications, the input disconnect also prevents battery depletion.

The MP3435 features a 10mΩ low-side MOSFET (LS-FET) and a 15mΩ synchronous high-side MOSFET (HS-FET) for high efficiency and low cost. The MP3435's fault protections include under-voltage lockout (UVLO), current limiting, and thermal shutdown (TSD).

The MP3435 is available in a low-profile QFN-20 (3mmx4mm) package.

ELECTRICAL SPECIFICATIONS

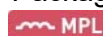
Parameter	Symbol	Value	Units
Input voltage	V_{IN}	3 to 10	V
Output voltage	V_{OUT}	12	V
Output current	I_{OUT}	0 to OCP ⁽¹⁾	A

Note:

- 1) The maximum output current depends on the current limit, permitted temperature rising, and input voltage.

FEATURES

- Wide 3V to 20V Operating Input Range
- Up to 22V Output Voltage
- Integrated 10mΩ LS-FET and 15mΩ Synchronous HS-FET
- 19A Internal Switch Current Limit or External Configurable Input Current Limit
- Input Disconnect and Output Short-Circuit Protection (SCP)
- External Soft Start (SS) and Compensation
- Configurable UVLO and Hysteresis
- <1μA Shutdown Current
- Thermal Shutdown (TSD) at 150°C
- Available in a QFN-20 (3mmx4mm) Package

 Optimized Performance with MPS Inductor MPL-AY1050 Series

APPLICATIONS

- Thunderbolt Interfaces
- Notebooks and Tablets
- Bluetooth Audio
- Power Banks
- Fuel Cells
- Point-of-Sale (POS) Systems
- Other Electronic Accessories

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EVL3435-L-00A EVALUATION BOARD

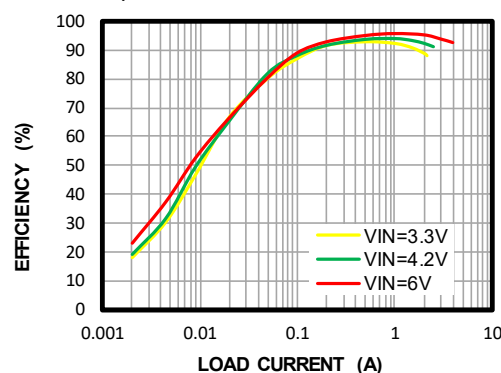


LxWxH (6.4cmx6.4cmx0.6cm)

Board Number	MPS IC Number	MPS Inductor
EVL3435-L-00A	MP3435GL	MPL-AY1050-1R5

Efficiency

Input MOSFET, $V_{OUT} = 12V$



QUICK START GUIDE

The output voltage (V_{OUT}) of the evaluation board is 12V. The board layout accommodates most commonly used components.

1. Preset the power supply between 3V and 10V.
2. Turn off the power supply.
3. Connect the power supply terminals to:
 - a. Positive (+): VIN
 - b. Negative (-): GND
4. Connect the load terminals to:
 - a. Positive (+): VOUT
 - b. Negative (-): GND
5. After making the connections, turn on the power supply.
6. Once the input voltage (V_{IN}) is applied, the MP3435 is enabled on the evaluation board.
7. V_{OUT} can be changed by modifying the R2 resistor's value. The new V_{OUT} can be calculated with Equation (1):

$$V_{OUT} = V_{FB} \times \left(1 + \frac{R1}{R2}\right) \quad (1)$$

Where V_{FB} is 1.225V, and R1 is 300k Ω .

8. The default configuration of the evaluation board uses an external sense resistor. To use the internal sense resistor, follow steps 9 through 11 to modify the evaluation board.
9. Connect the GATE pin to GND via a 0 Ω resistor (R7).
10. Set the external sense resistor (R4_A, R4_B, R4_C, and R4_D) to 0 Ω .
11. Short the input MOSFET (Q1) drain to source.
12. After modifying the evaluation board, follow steps 1 through 5. The MP3435 should automatically use the internal sense resistor.

EVALUATION BOARD SCHEMATIC

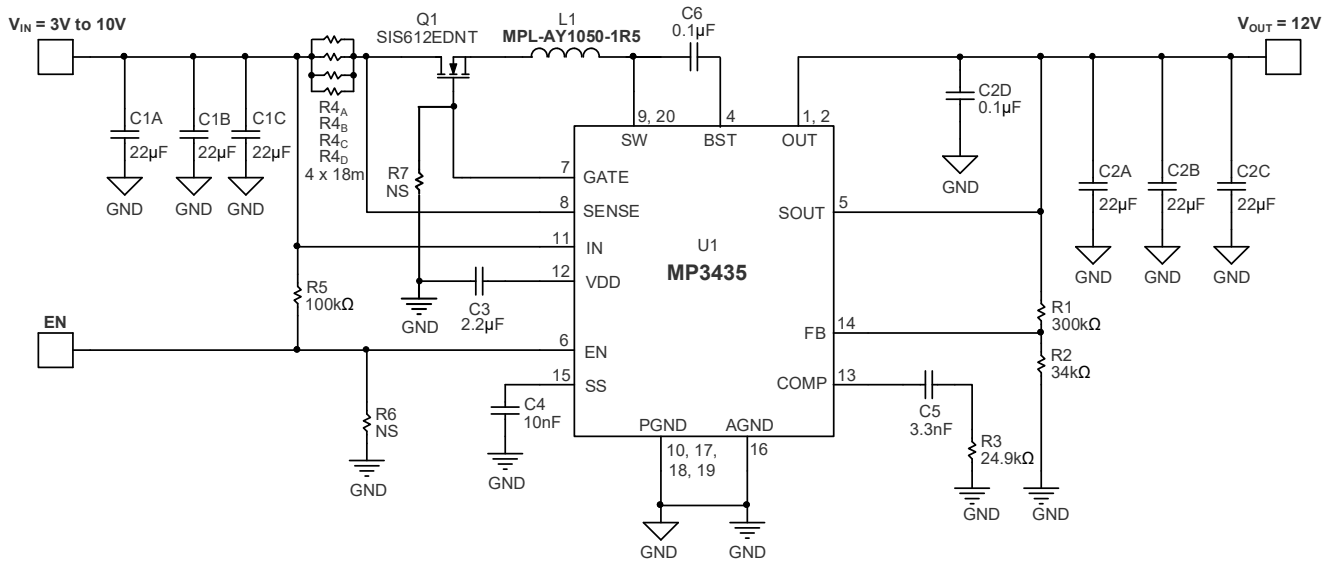


Figure 1: Evaluation Board Schematic

EVL3435-L-00A BILL OF MATERIALS

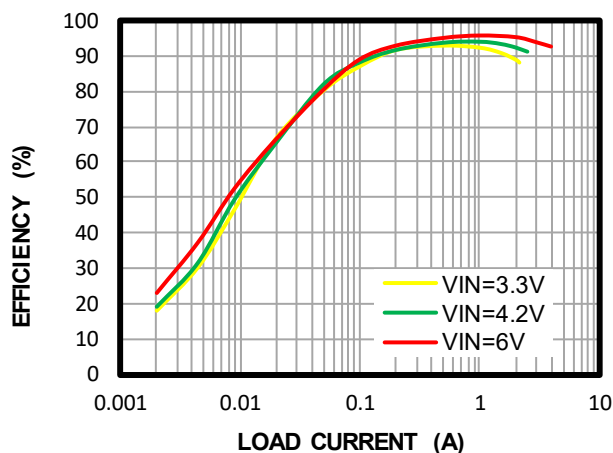
Qty	Ref	Value	Description	Package	Manufacturer	Manufacturer P/N
1	L1	1.5μH	3.4mΩ, 17A inductor	SMD (11mmx10mm)	MPS	MPL-AY1050-1R5
6	C1A, C1B, C1C, C2A, C2B, C2C	22μF	Ceramic capacitor, 25V, X5R	1210	Murata	GRM32R71E226KL
2	C2D, C6	0.1μF	Ceramic capacitor, 25V, X5R	0603	Murata	GRM188R71E104KA9
1	C3	2.2μF	Ceramic capacitor, 10V, X5R	0805	Murata	GRM21AR71A225KL
1	C4	10nF	Ceramic capacitor, 50V, X5R	0603	Murata	GRM188R71H103KL
1	C5	3.3nF	Ceramic capacitor, 50V, X5R	0603	Murata	GRM188R71H332KL
1	Q1	20V	20V, 3.2mΩ, 19A N-channel MOSFET	PowerPAK 1212-8	Vishay	SiS612EDNT-T1-GE3
1	R1	300kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-07300KL
1	R2	34kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0734KL
1	R3	24.9kΩ	Film resistor, 1%	0603	Yageo	RC0603FR-0724K9L
4	R4 _A , R4 _B , R4 _C , R4 _D	18mΩ	Low-resistance film resistor, 1%	0805	Yageo	PR0805FKF070R018L
1	R5	100kΩ	Film resistor, 1%	0603	Yageo	RC0603JR-07100KL
0	R6, R7	NS				
1	U1	MP3435	22V, 19A boost converter	QFN-20 (3mmx4mm)	MPS	MP3435GL

EVB TEST RESULTS

$V_{IN} = 3.3V$, $V_{OUT} = 12V$, $L = 1.5\mu H$, $I_{OUT} = 2A$, $T_A = 25^{\circ}C$, unless otherwise noted.

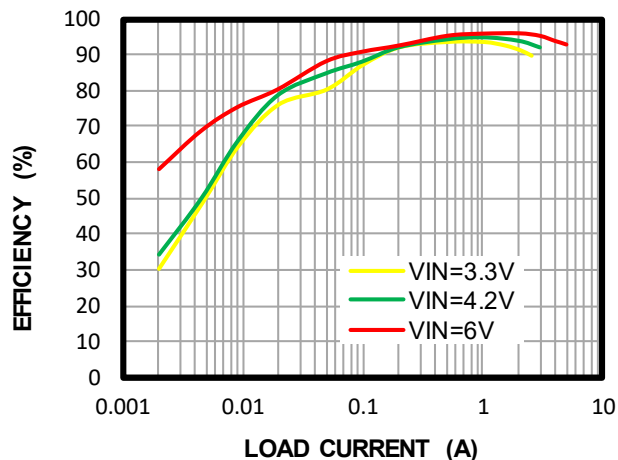
Efficiency vs. Load Current

Input MOSFET

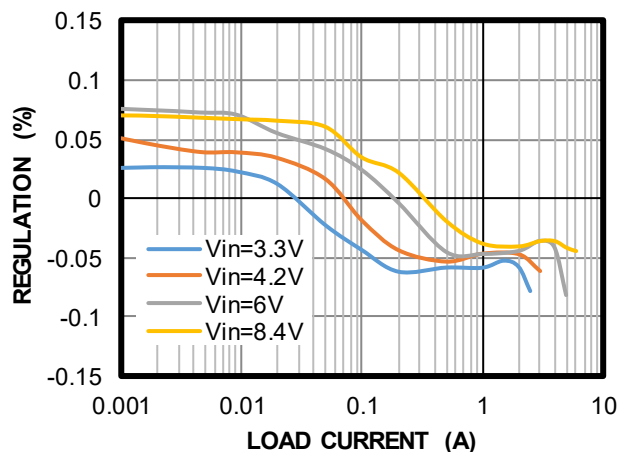


Efficiency vs. Load Current

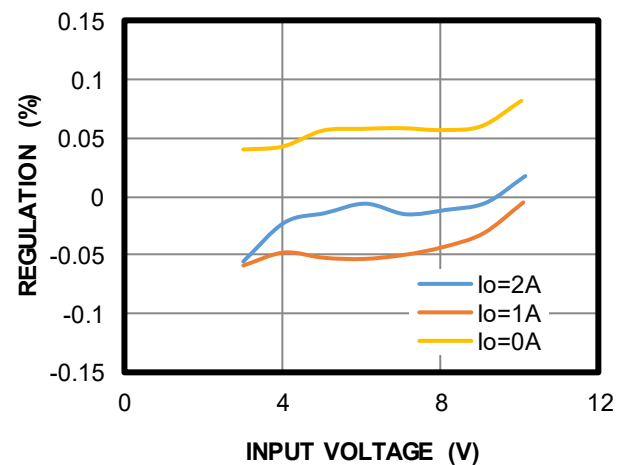
No input MOSFET, GATE = GND



Load Regulation

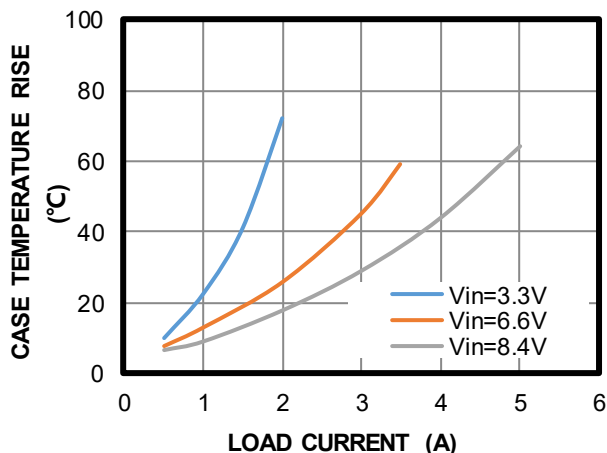


Line Regulation



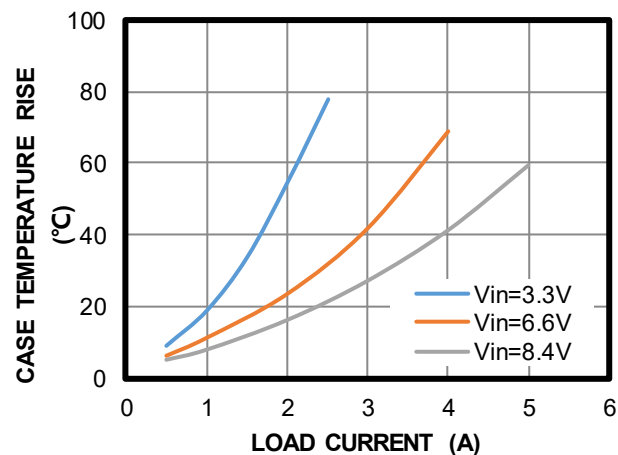
Case Temperature Rise

Input MOSFET



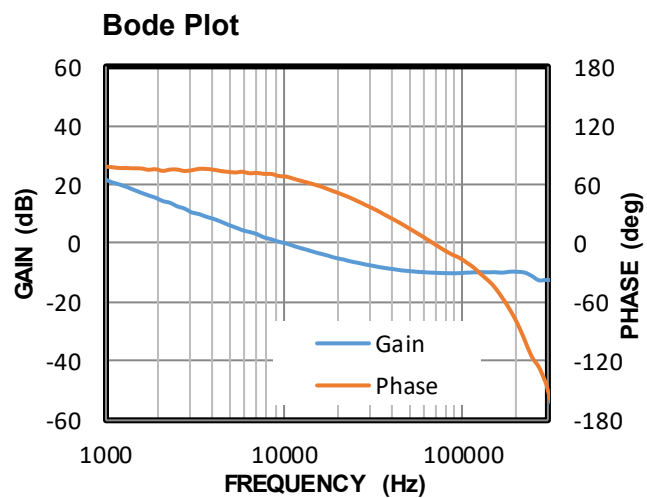
Case Temperature Rise

No input MOSFET, GATE = GND



EVB TEST RESULTS *(continued)*

$V_{IN} = 3.3V$, $V_{OUT} = 12V$, $L = 1.5\mu H$, $I_{OUT} = 2A$, $T_A = 25^\circ C$, unless otherwise noted.



EVB TEST RESULTS (continued)

$V_{IN} = 3.3V$, $V_{OUT} = 12V$, $L = 1.5\mu H$, $I_{OUT} = 2A$, $T_A = 25^{\circ}C$, unless otherwise noted.

Steady State

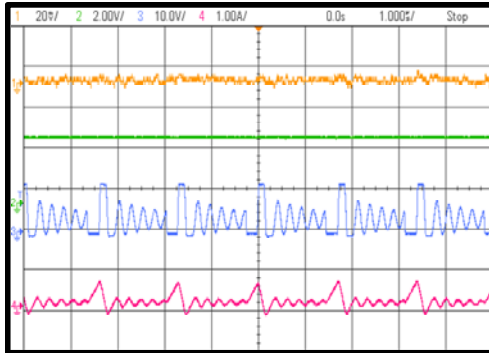
$I_{OUT} = 0A$

CH1: $V_{OUT/AC}$

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L



Steady State

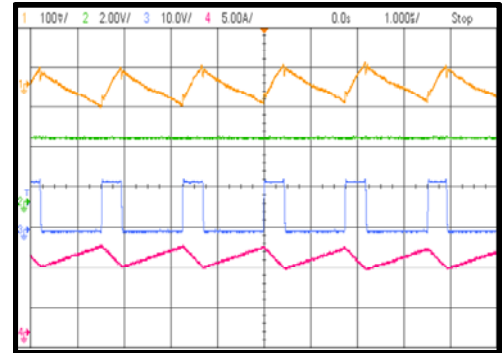
$I_{OUT} = 2A$

CH1: $V_{OUT/AC}$

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L



Start-Up through VIN

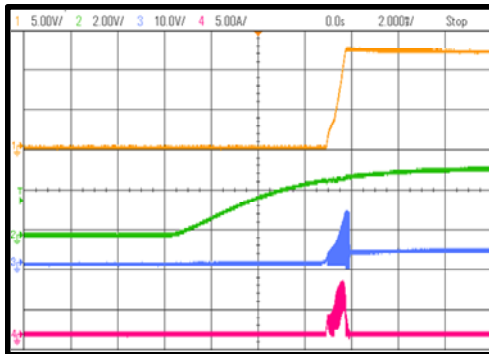
$I_{OUT} = 0A$

CH1: V_{OUT}

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L



Start-Up through VIN

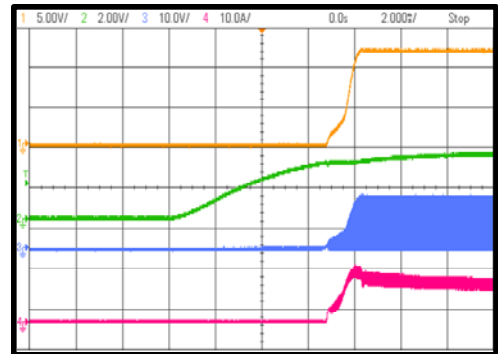
$I_{OUT} = 2A$

CH1: V_{OUT}

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L



Shutdown through VIN

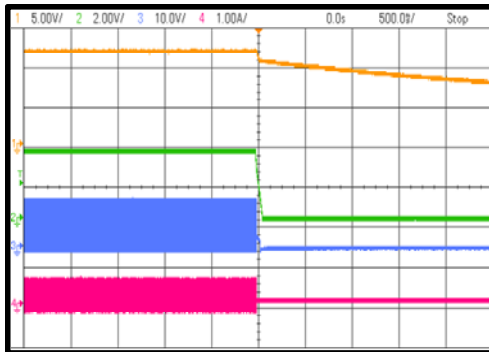
$I_{OUT} = 0A$

CH1: V_{OUT}

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L



Shutdown through VIN

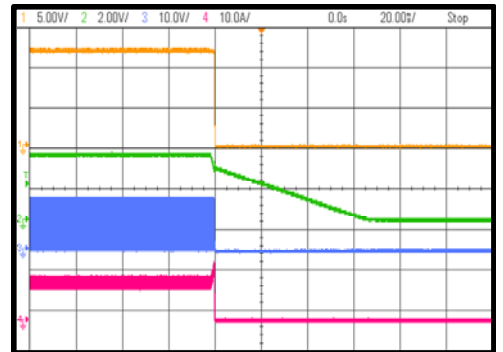
$I_{OUT} = 2A$

CH1: V_{OUT}

CH2: V_{IN}

CH3: V_{SW}

CH4: I_L

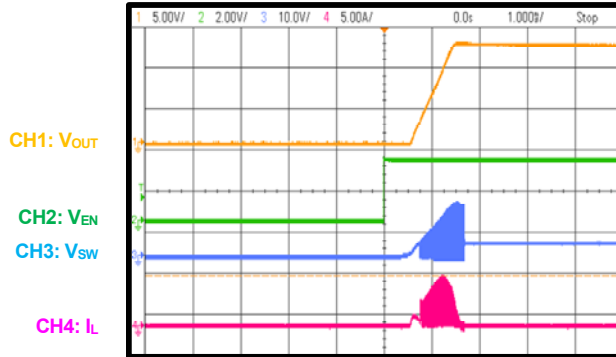


EVB TEST RESULTS (continued)

$V_{IN} = 3.3V$, $V_{OUT} = 12V$, $L = 1.5\mu H$, $I_{OUT} = 2A$, $T_A = 25^{\circ}C$, unless otherwise noted.

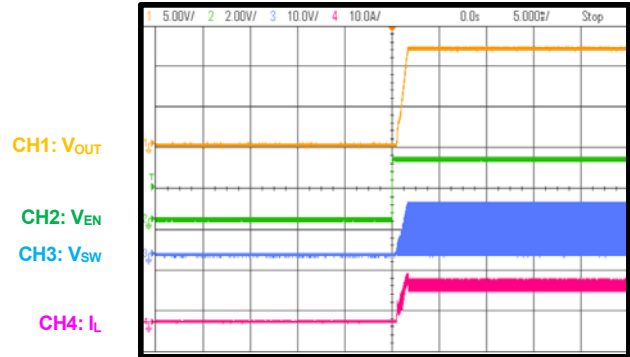
Start-Up through EN

$I_{OUT} = 0A$



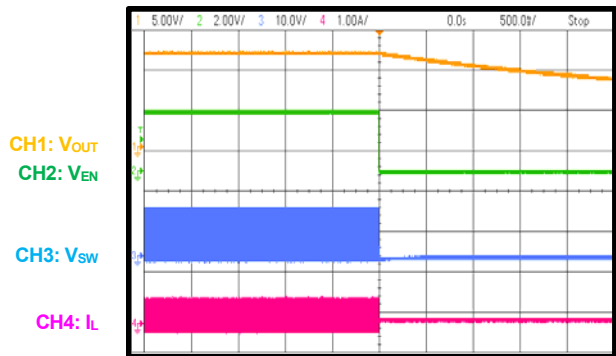
Start-Up through EN

$I_{OUT} = 2A$



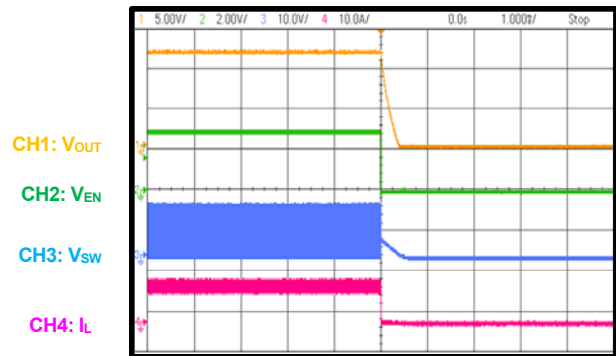
Shutdown through EN

$I_{OUT} = 0A$



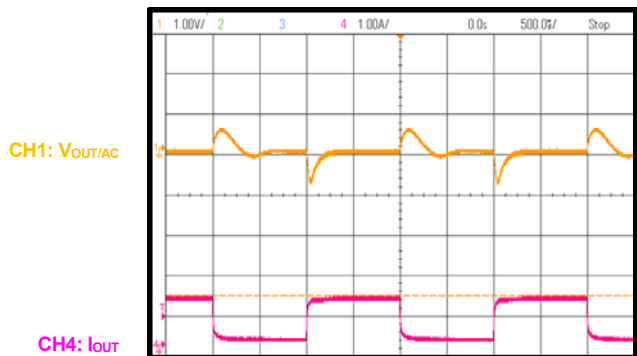
Shutdown through EN

$I_{OUT} = 2A$



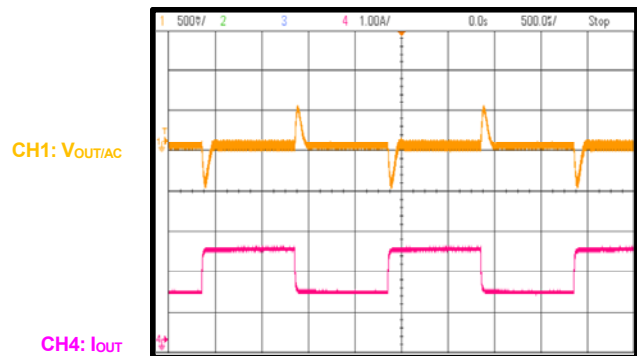
Load Transient

$I_{OUT} = 0A$ to $1A$, $I_{RAMP} = 25mA/\mu s$



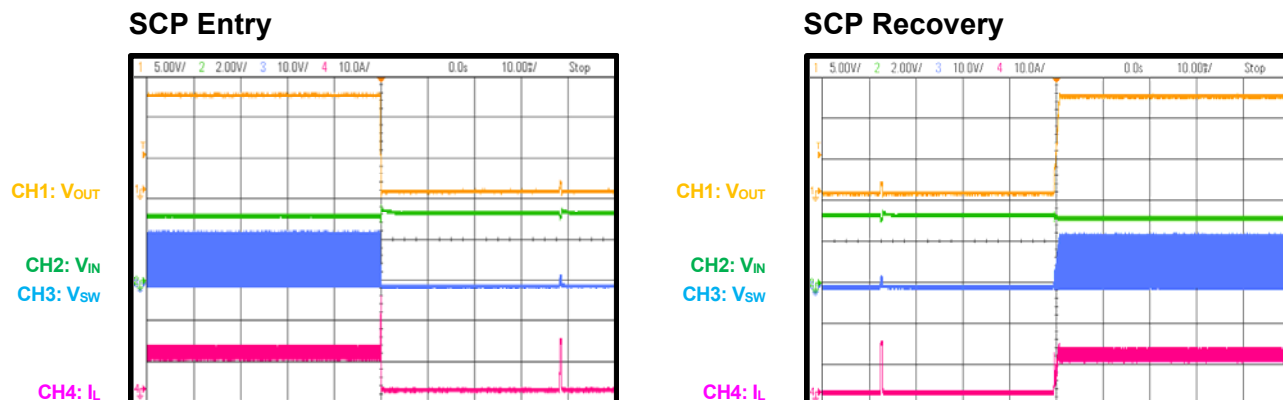
Load Transient

$I_{OUT} = 1A$ to $2A$, $I_{RAMP} = 25mA/\mu s$



EVB TEST RESULTS *(continued)*

$V_{IN} = 3.3V$, $V_{OUT} = 12V$, $L = 1.5\mu H$, $I_{OUT} = 2A$, $T_A = 25^{\circ}C$, unless otherwise noted.



PCB LAYOUT

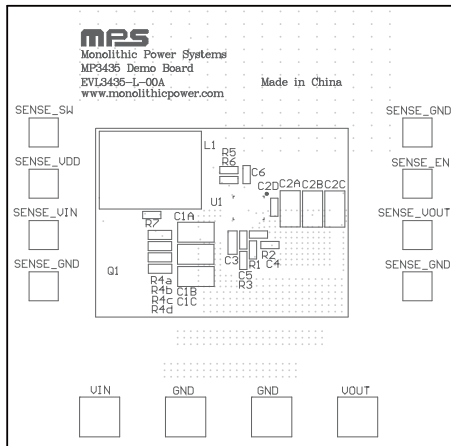


Figure 1: Top Silk

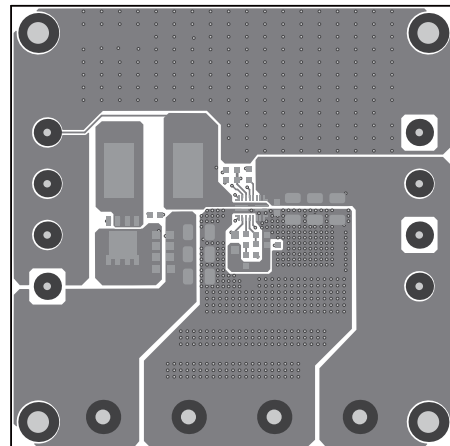


Figure 2: Top Layer

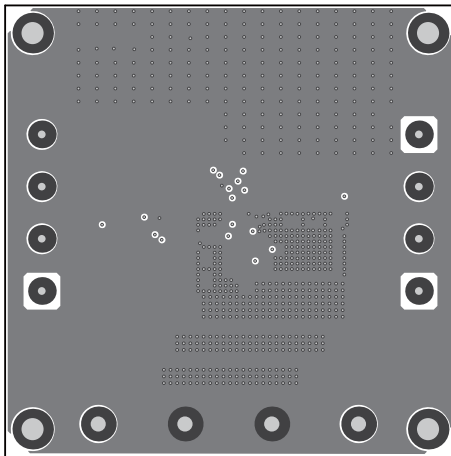


Figure 3: Mid-Layer 1

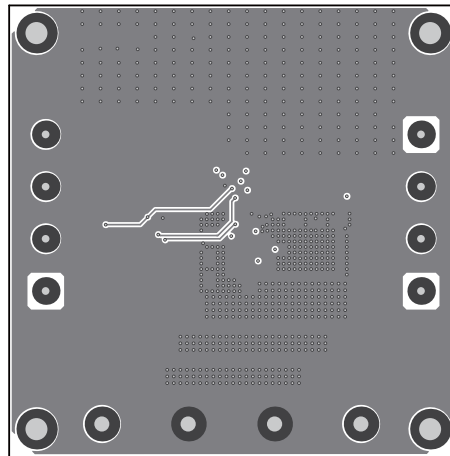


Figure 4: Mid-Layer 2

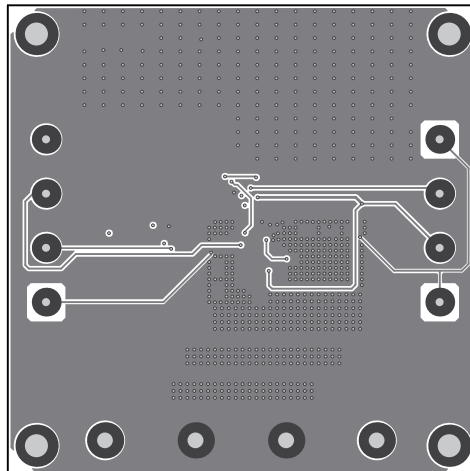


Figure 5: Bottom Layer

REVISION HISTORY

Revision #	Revision Date	Description	Pages Updated
1.0	2/4/2021	Initial Release	-

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